



Docket No.: MUH-12728

I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class Mail in an envelope addressed to the Commissioner for Patents, P.O. Pox 1450, Alexandria, VA 22313-1450 on the date indicated below.

By:_____ Date

Date: <u>March 2, 2006</u>

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applic. No. : 10/631,350 Confirmation No: 1926

Applicant : Hans Weber, et al. Filed : July 31, 2003

Art Unit : 2818

Examiner : Dao H. Nguyen

Title : Method for Forming a Channel Zone of a Transistor

and NMOS Transistor

Docket No. : MUH-12728

Customer No. : 24131

Date of Notice of Allowance : December 2, 2005

LETTER

Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450

Sir:

Please note that the German Priority document number 102 35 000.0 dated July 31, 2002 was filed on September 25, 2003 in the U.S Patent Office. Please find enclosed copies of the following:

- 1) Claim for Priority
- 2) The cover page of priority document; and
- 3) The return postcard indicating receipt by the PTO.

Respectfully submitted,

Reg. No. 41,947

Date: March 2, 2006

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/mj

Docket No.: MUH-12728

TRANSPINE TRA

By: Date: September 23, 2003

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant

Hans Weber et al.

Appl. No.

10/631,350

Filed

20231.

July 31, 2003

Title

Method for Forming a Channel Zone of a Transistor and PMOS

Transistor

CLAIM FOR PRIORITY

Hon. Commissioner for Patents, Alexandria, VA 22313-1450 Sir:

Claim is hereby made for a right of priority under Title 35, U.S. Code, Section 119, based upon the German Patent Application 102 35 000.0 filed July 31, 2002.

A certified copy of the above-mentioned foreign patent application is being submitted herewith.

Respectfully submitted,

OREGORY / MAYBACK

KEY. NY 40,7 16

Date: September 23, 2003

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/mjb

BUNDESREPUBLIK DEUTSCHLAND





Prioritätsbescheinigung über die Einreichung einer Patentanmeldung

Aktenzeichen:

102 35 000.0

Anmeldetag:

31. Juli 2002

Anmelder/Inhaber:

Infineon Technologies AG, München/DE

Bezeichnung:

Verfahren zur Bildung einer Kanalzone eines

Transistors und PMOS-Transistor

IPC:

H 01 L 21/336

Die angehefteten Stücke sind eine richtige und genaue Wiedergabe der ursprünglichen Unterlagen dieser Patentanmeldung.

München, den 11. Juli 2003

Deutsches Patent- und Markenamt

Der Präsident Im Auftrag



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Applic pgs . . . Rule 53b New 🗆 Contin 🗀 Div 🗀 CIP 🗀 / Rule 53c Prov. 🗀 / Rule 53d CPA . . . RCE 🗀 The stamp of the Patent Office hereon may be considered the date on which papers indicated below were received. ☐ Design ☐... Dwgs Lande Declaration Propertient .. Mailed .. Sept. 23, 2003 APPLIC. NO. 10/631, 350 Express Mail ☐ PCT Cover Sheet WO. ☐ Amend pgs . . . ☐ Prel. Amend pgs . . . ØLetter □ Briefpgs...□Appndx pgs...□I.D.S.+... Refs.
□ Assoc Pwr of Atty (□ Credit Card \$ /3€ ☐ Response pgs . . . ☐ 37CFR1.116 ☐ Not. of Appeal ☐ File rec. corr □ PTOL . . . □ Check \$ ~.. (Patent Office. Please stamp and return to addressee on reverse side.) EPriority Claim EPCert. Prior. Doc(s) ☐ Pet. for Ext Mo. ☐ Pet ☐ Cert. of Corr. CKE'L NO. MUH-12728 Assignment Assignment CIP...pgs □ Cert. Trans. ☐ Issue Fee